# 2SB0766, 2SB0766A (2SB766, 2SB766A)

## Silicon PNP epitaxial planar type

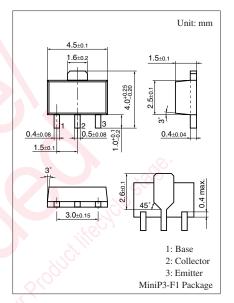
For low-frequency output amplification Complementary to 2SD0874 (2SD874A), 2SD0874A (2SD874A)

#### ■ Features

- Large collector power dissipation P<sub>C</sub>
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB0766	V <sub>CBO</sub>	-30	V
(Emitter open)	2SB0766A		-60	
Collector-emitter voltage	2SB0766	V <sub>CEO</sub>	-25	V
(Base open)	2SB0766A		-50	
Emitter-base voltage (Col	V <sub>EBO</sub>	-5	V	
Collector current	$I_{\rm C}$	-1	A	
Peak collector current	$I_{CP}$	-1.5	A	
Collector power dissipation	P <sub>C</sub>	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	



#### Marking Symbol:

2SB0766: A2SB0766A: B

Note) \*: Print circuit board: Copper foil area of 1 cm<sup>2</sup> or more, and the board thickness of 1.7 mm for the collector portion.

### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter		Symbol	mbol Conditions		Тур	Max	Unit
Collector-base voltage	2SB0766	V <sub>CBO</sub>	$I_C = -10 \mu\text{A}, I_E = 0$	-30	00/1		V
(Emitter open)	2SB0766A	dille	die die giz dille	-60	8		
Collector-emitter voltage	2SB0766	V <sub>CEO</sub>	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-25			V
(Base open)	2SB0766A		9/31 9/3 VO CO	-50			
Emitter-base voltage (Collector open)		$V_{EBO}$	$I_E = -10 \ \mu A, I_C = 0$	-5			V
Collector-base cutoff current (Emitter open)		$I_{CBO}$	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Forward current transfer ratio *1		h <sub>FE1</sub> *2	$V_{CE} = -10 \text{ V}, I_C = -500 \text{ mA}$	85		340	_
		h <sub>FE2</sub>	$V_{CE} = -5 \text{ V}, I_C = -1 \text{ A}$	50			
Collector-emitter saturation voltage *1		V <sub>CE(sat)</sub>	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		- 0.2	- 0.4	V
Base-emitter saturation voltage *1		V <sub>BE(sat)</sub>	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		- 0.85	-1.20	V
Transition frequency		$f_T$	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		20	30	pF
(Common base, input open circuited)							

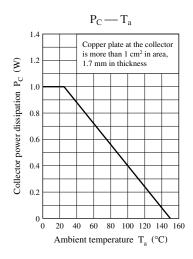
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

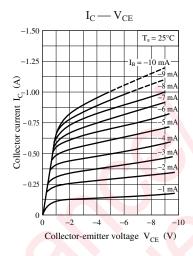
#### 2. \*1: Pulse measurement

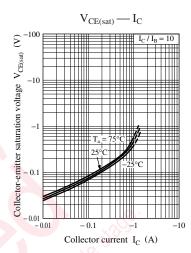
#### \*2: Rank classification

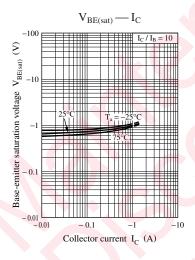
Rank	Q	R	S	
$h_{FE1}$	85 to 170	120 to 240	170 to 340	

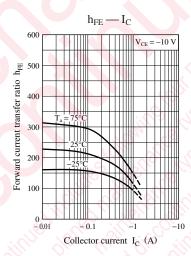
Note) The part numbers in the parenthesis show conventional part number.

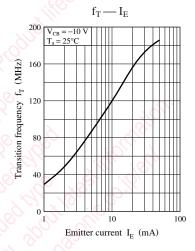


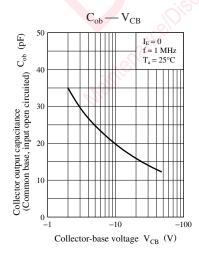


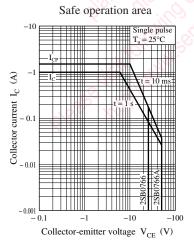












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